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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/552,728	10/11/2005	Koso Fujino	017700-0179	9461
23392 FOLEY & LAR	7590 11/10/200 RDNER	EXAMINER		
555 South Flow SUITE 3500		WARTALOWICZ, PAUL A		
LOS ANGELES, CA 90071-2411			ART UNIT	PAPER NUMBER
			1793	
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			11/10/2009	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Annlicant(a)			
	Application No.	Applicant(s)			
	10/552,728	FUJINO ET AL.			
Office Action Summary	Examiner	Art Unit			
	PAUL A. WARTALOWICZ	1793			
The MAILING DATE of this communication a Period for Reply	ppears on the cover sheet with the	e correspondence address			
A SHORTENED STATUTORY PERIOD FOR REP WHICHEVER IS LONGER, FROM THE MAILING - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory perioder a Failure to reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the main earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNICATION 1.136(a). In no event, however, may a reply be ad will apply and will expire SIX (6) MONTHS froute, cause the application to become ABANDO	ON. timely filed om the mailing date of this communication. NED (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on <u>30</u>	<u>June 2009</u> .				
2a) This action is FINAL . 2b) ⊠ Th	This action is FINAL . 2b)⊠ This action is non-final.				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under	r <i>Ex parte Quayle</i> , 1935 C.D. 11,	453 O.G. 213.			
Disposition of Claims					
4) Claim(s) 3-16 is/are pending in the application 4a) Of the above claim(s) is/are withdrest is/are allowed. 5) Claim(s) is/are allowed. 6) Claim(s) 3-16 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and	rawn from consideration.				
Application Papers					
9) The specification is objected to by the Examination The drawing(s) filed on is/are: a) and a Applicant may not request that any objection to the Replacement drawing sheet(s) including the correction. 11) The oath or declaration is objected to by the least of the specific state.	ccepted or b) objected to by the objected to by the drawing(s) be held in abeyance. Section is required if the drawing(s) is	See 37 CFR 1.85(a). objected to. See 37 CFR 1.121(d).			
Priority under 35 U.S.C. § 119					
12) ☐ Acknowledgment is made of a claim for foreign a) ☐ All b) ☐ Some * c) ☐ None of: 1. ☐ Certified copies of the priority docume 2. ☐ Certified copies of the priority docume 3. ☐ Copies of the certified copies of the priority docume application from the International Bure * See the attached detailed Office action for a list	nts have been received. nts have been received in Applicationity documents have been rece eau (PCT Rule 17.2(a)).	ation No ived in this National Stage			
Attachment(s) 1) Notice of References Cited (PTO-892)	4) ☐ Interview Summa				
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date 7/8/9.	Paper No(s)/Mail 5) Notice of Informa 6) Other:	Date Il Patent Application			

DETAILED ACTION

Response to Arguments

Applicant's arguments with respect to claims 3-16 have been considered but are moot in view of the new ground(s) of rejection.

Applicant argues that Akedo discloses using a pressure apparatus to press a deposited film and that the teaching in Akedo does not address the step of planarizing a textured metal substrate.

However, Akedo is not relied upon to teach planarizing a textured metal substrate. Akedo is only relied upon to teach a means of planarization. Eyidi teaches planarizing by a rolling method but fails only to recite the apparatus in which to carry out the rolling planarization as discussed, *infra*. One of ordinary skill in the art would recognize that using a mirror roller to planarize a surface as taught by Akedo would be equally applicable to the process of Eyidi because both Eyidi and Akedo teach methods of planarization by rolling.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

The factual inquiries set forth in *Graham* **v.** *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

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1. Determining the scope and contents of the prior art.

- 2. Ascertaining the differences between the prior art and the claims at issue.
- 3. Resolving the level of ordinary skill in the pertinent art.
- 4. Considering objective evidence present in the application indicating obviousness or nonobviousness.

Claims 3, 9, 15, and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Eyidi et al. ("Growth of CeO₂ thin films…") in view of Hans Thieme et al. (US 6458223) and JP 07-105750 (hereinafter '750: please refer to the machine translation attached to this office action) and Hsu (US 6569745).

Eyidi teaches a method of making a superconducting (pg 15) wherein nickel substrates are hot rolled and then hot rolled, cold rolled to achieve a certain deformation (this appears to be a planarizing step), annealed, cleaned wherein after cleaning an intermediate layer of CeO2 is deposited therein, wherein a YBCO superconductor is disposed thereon (pg 20).

Eyidi fails to teach the planarizing depth, the crystal axis offset, and the surface roughness.

'750 teaches a superconductor wire [0001] wherein the angle Φ (made by the normal X of the crystal surface and the Y of the polycrystalline metal base body) is less than 15° and angle θ formed by connecting crystal particles is less than 10° (Abstract, [0023]) for the purpose of reducing micro unevenness of the grain boundary [0023].

Therefore, it would have been obvious to one of ordinary skill in the art at the time applicant's invention was made to provide a substrate having an angle Φ (made by the normal X of the crystal surface and the Y of the polycrystalline metal base body) is less than 15° and angle θ formed by connecting crystal particles is less than 10°

(Abstract, [0023]) in Eyidi in order to reduce micro unevenness of the grain boundary [0023] as taught by '750.

It appears that the angles disclosed in '750, namely that the angle Φ (made by the normal X of the crystal surface and the Y of the polycrystalline metal base body) is less than 15° and angle θ formed by connecting crystal particles is less than 10° (Abstract, [0023]) overlaps with and inherently meets the limitation of crystal axis offset relative to an orientation axis by at most 10°.

If '750 does not inherently teach a crystal axis offset relative to an orientation axis by at most 10°, it would be obvious to reduce the crystal axis offset relative to an orientation axis to overlap with a range of at most 10° because '750 teaches that reducing micro unevenness of the grain boundary is desired for superconductor properties [0023].

Hans Thieme et al. teach a method of making a superconductor (col. 1) wherein the roughness of the substrate corresponds to the current carrying capability of the superconductor film wherein the roughness is 10-20 nm Ra (col. 11-12).

Therefore, it would have been obvious to one of ordinary skill in the art at the time applicant's invention was made to provide a roughness of 10-20 nm Ra (col. 11-12) for the metal substrate in Eyidi in order to maintain a certain current carrying capability of the superconductor film (col. 11-12) as taught by Hans Thieme et al.

Hsu teaches a method of making a superconducting article (col. 1) wherein it is known to planarize a layer to a thickness of between 50-500 nm (col. 2).

Therefore, it would have been obvious to one of ordinary skill in the art to planarize a layer to a thickness of between 50-500 nm (col. 2) in Eyidi in order to produce a superconducting article as taught by Hsu.

Claims 6, 12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Eyidi et al. ("Growth of CeO₂ thin films…") in view of Hans Thieme et al. (US 6458223) and JP 07-105750 (hereinafter '750: please refer to the machine translation attached to this office action) and Hsu (US 6569745) and Akedo et al. (US 6827634).

Eyidi teach a method of making a superconductor as described above in claim 3. Eyidi teaches rolling the substrate (pg 15).

Akedo teaches a method for depositing a layer on a substrate (col. 1) wherein it is known to use a mirror roller for the purpose of planarizing a material layer (col. 5).

Therefore, it would have been obvious to one of ordinary skill in the art at the time applicant's invention was made to provide a mirror roller in Eyidi in order to carry out planarization as taught by Akedo et al.

Claims 4, 5, 10, 11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Eyidi et al. ("Growth of CeO₂ thin films…") in view of Hans Thieme et al. (US 6458223) and JP 07-105750 (hereinafter '750: please refer to the machine translation attached to this office action) and Hsu (US 6569745) and Goyal et al. (US 6451450).

Eyidi teach a method as described above in claim 3.

Eyidi teaches annealing the substrate after planarization for the purpose of forming a biaxial cube texture (pg 15) but fails to teach the conditions of the annealing step.

Goyal however teaches a method of making a superconductor (col. 1) wherein a substrate is annealed in a vacuum furnace or reducing gas for the purpose of forming a cube texture (col. 5).

Therefore, it would have been obvious to one of ordinary skill in the art at the time applicant's invention was made to provide the substrate annealed in a vacuum furnace or reducing gas in Eyidi in order to form a cube texture (col. 5) as taught by Goyal et al.

Claims 7,8, 13, 14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Eyidi et al. ("Growth of CeO₂ thin films…") in view of Hans Thieme et al. (US 6458223) and JP 07-105750 (hereinafter '750: please refer to the machine translation attached to this office action) and Hsu (US 6569745) and Goyal et al. (US 6451450) and Akedo et al. (US 6827634).

Eyidi teach a method as described above in claim 3.

Eyidi teaches annealing the substrate after planarization for the purpose of forming a biaxial cube texture (pg 15) but fails to teach the conditions of the annealing step.

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Goyal however teaches a method of making a superconductor (col. 1) wherein a substrate is annealed in a vacuum furnace or reducing gas for the purpose of forming a cube texture (col. 5).

Therefore, it would have been obvious to one of ordinary skill in the art at the time applicant's invention was made to provide the substrate annealed in a vacuum furnace or reducing gas in Eyidi in order to form a cube texture (col. 5) as taught by Goyal et al.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to PAUL A. WARTALOWICZ whose telephone number is (571)272-5957. The examiner can normally be reached on 8:30-6 M-Th and 8:30-5 on Alternate Fridays.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Stanley Silverman can be reached on (571) 272-1358. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Paul Wartalowicz November 7, 2009

/Stanley Silverman/ Supervisory Patent Examiner, AU 1793